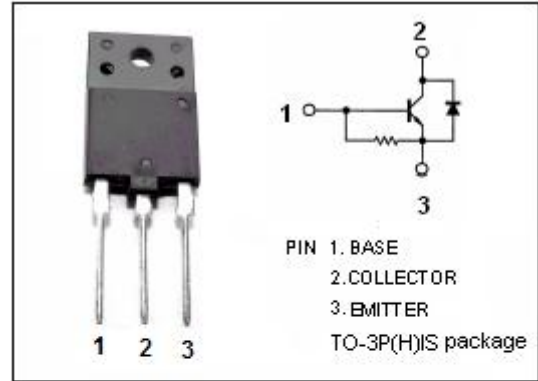


isc Silicon NPN Power Transistor

2SC4766

DESCRIPTION

- High Breakdown Voltage-
: $V_{CBO} = 1700V$ (Min)
- High Switching Speed
- Low Saturation Voltage
- Built-in Damper Diode
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

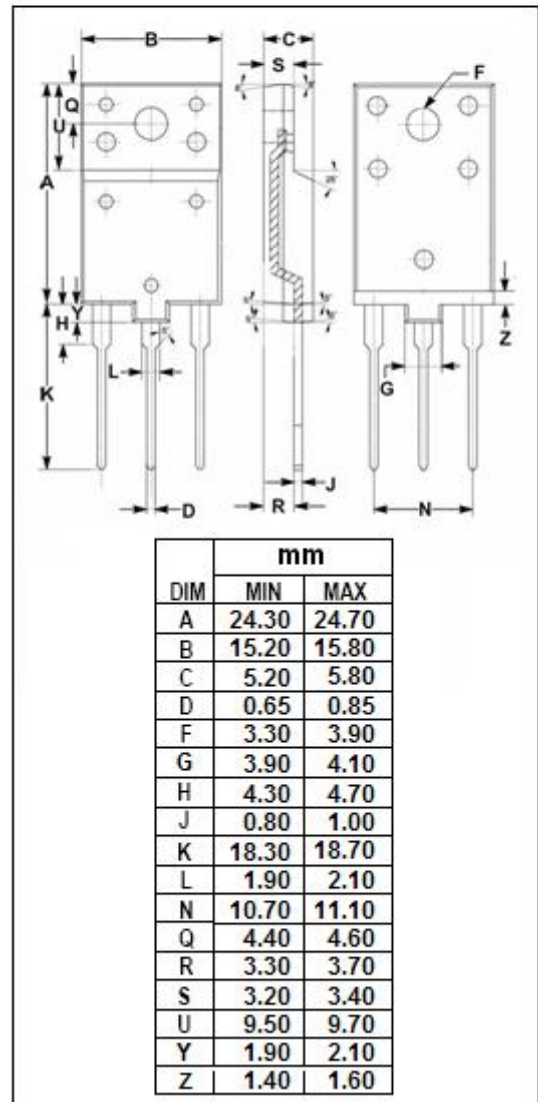


APPLICATIONS

- Horizontal deflection output for medium resolution display.

ABSOLUTE MAXIMUM RATINGS ($T_a = 25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{CBO}	Collector-Base Voltage	1700	V
V_{CEO}	Collector-Emitter Voltage	600	V
V_{EBO}	Emitter-Base Voltage	5	V
I_C	Collector Current- Continuous	± 6	A
I_{CP}	Collector Current-Pulse	± 12	A
I_B	Base Current- Continuous	3	A
P_C	Collector Power Dissipation @ $T_c = 25^\circ C$	50	W
T_J	Junction Temperature	150	$^\circ C$
T_{stg}	Storage Temperature Range	-55~150	$^\circ C$



isc Silicon NPN Power Transistor

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ELECTRICAL CHARACTERISTICS

T_c=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 300mA ; I _C = 0	5			V
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 4.5A; I _B = 1.3A			5.0	V
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 4.5A; I _B = 1.3A			1.5	V
I _{CBO}	Collector Cutoff Current	V _{CB} = 1700V ; I _E = 0			1.0	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V ; I _C = 0	66		200	mA
h _{FE-1}	DC Current Gain	I _C = 1A ; V _{CE} = 5V	8			
h _{FE-2}	DC Current Gain	I _C = 4.5A ; V _{CE} = 5V	3.5		7.5	
V _{ECF}	C-E Diode Forward Voltage	I _F = 4.5A			2.0	V
f _T	Current-Gain—Bandwidth Product	I _C = 0.1A ; V _{CE} = 10V		3		MHz
C _{OB}	Output Capacitance	I _E =0 ; V _{CB} =10V; f _{test} =1.0MHz		250		pF

Switching times; Resistive load

t _{stg}	Storage Time	I _C = 4.5A , I _{B1} = 0.9A ; I _{B2} = -1.8A R _L = 43 Ω			3.0	μ s
t _f	Fall Time				0.2	μ s

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